REVISIONS			
LTR	DESCRIPTION	DATE (YR-MO-DA)	APPROVED

REV																			
PAGE																			
REV																			
PAGE																			

REV STATUS OF PAGES	REV															
	PAGE	1	2	3	4	5	6	7	8	9	10	11				

PMIC N/A

MILITARY DRAWING

THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE

AMSC N/A

PREPARED BY
James E. Nicklaus

CHECKED BY
D. A. DiCenzo

APPROVED BY
Robert P. Evans

DRAWING APPROVAL DATE
13 October 1987

REVISION LEVEL

DEFENSE ELECTRONICS SUPPLY CENTER
DAYTON, OHIO 45444

TITLE: MICROCIRCUITS, DIGITAL, TRIPLE 3-INPUT OR GATE MCMOS, MONOLITHIC SILICON

SIZE	CODE IDENT NO	DWG NO.
A	67268	5962-87722

PAGE 1 OF 11

5962-E597-2

1. SCOPE

1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".

1.2 Part number. The complete part number shall be as shown in the following example:

5962-87722	01	C	X
Drawing number	Device type (1.2.1)	Case outline (1.2.2)	Lead finish per MIL-M-38510

1.2.1 Device type. The device type shall identify the circuit function as follows:

Device type	Generic number	Circuit function
01	54HC4075	Triple 3-input OR gate

1.2.2 Case outlines. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter	Case outline
C	D-1 (14-lead, 1/4" x 3/4"), dual-in-line package
D	F-2 (14-lead, 1/4" x 3/8"), flat package
2	C-2 (20-terminal, .350" x .350"), square chip carrier package

1.3 Absolute maximum ratings. 1/

Supply voltage range	-0.5 V dc to +7.0 V dc
DC input voltage	-0.5 V dc to V_{CC} +0.5 V dc
DC output voltage	-0.5 V dc to V_{CC} +0.5 V dc
Clamp diode current	±20 mA
DC output current (per pin)	±25 mA
DC V_{CC} or GND current (per pin)	±50 mA
Storage temperature range	-65°C to +150°C
Maximum power dissipation (P_D) 2/	500 mW
Lead temperature (soldering, 10 seconds)	+260°C
Thermal resistance, junction-to-case (Θ_{JC}):	
Case C, D, and 2	See MIL-M-38510, appendix C
Junction temperature (T_J)	+175°C

1.4 Recommended operating conditions.

Supply voltage (V_{CC})	+2.0 V dc to +6.0 V dc
Case operating temperature range (T_C)	-55°C to +125°C
Input rise or fall time:	
V_{CC} = 2.0 V	0 to 1000 ns
V_{CC} = 4.5 V	0 to 500 ns
V_{CC} = 6.0 V	0 to 400 ns

1/ Unless otherwise specified, all voltages are referenced to ground.

2/ For T_C = +100°C to +125°C, derate linearly at 12 mW/°C.

2. APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510 - Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883 - Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.

3.2.1 Terminal connections and logic diagram. The terminal connections and logic diagram shall be as specified on figure 1.

3.2.2 Truth table. The truth table shall be as specified on figure 3.

3.2.3 Switching waveforms. The switching waveforms shall be as specified on figure 2.

3.2.4 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.

3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full recommended case operating temperature range.

3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.

TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions 1/ $-55°C \le T_C \le +125°C$		Group A subgroups	Limits		Unit
					Min	Max	
High level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL} $\lvert I_O \rvert \le 20$ µA	$V_{CC} = 2.0$ V	1,2,3	1.9		V
			$V_{CC} = 4.5$ V		4.4		
			$V_{CC} = 6.0$ V		5.9		
		$\lvert I_O \rvert \le 4.0$ mA	$V_{CC} = 4.5$ V		3.7		
		$\lvert I_O \rvert \le 5.2$ mA	$V_{CC} = 6.0$ V		5.2		
Low level output voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL} $\lvert I_O \rvert \le 20$ µA	$V_{CC} = 2.0$ V	1,2,3		0.1	V
			$V_{CC} = 4.5$ V			0.1	
			$V_{CC} = 6.0$ V			0.1	
		$\lvert I_O \rvert \le 4.0$ mA	$V_{CC} = 4.5$ V			0.4	
		$\lvert I_O \rvert \le 5.2$ mA	$V_{CC} = 6.0$ V			0.4	
High level input voltage	V_{IH}	2/	$V_{CC} = 2.0$ V	1,2,3	1.5		V
			$V_{CC} = 4.5$ V		3.15		
			$V_{CC} = 6.0$ V		4.2		
Low level input voltage	V_{IL}	2/	$V_{CC} = 2.0$ V	1,2,3		0.3	V
			$V_{CC} = 4.5$ V			0.9	
			$v_C C = 6.0$ V			1.2	
Input capacitance	C_{IN}	$V_{IN} = 0$ V; $T_C = +25°C$ see 4.3.1c		4		10	pF

See footnotes at end of table.

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions 1/ $-55°C \le T_C \le +125°C$		Group A subgroups	Limits		Unit
					Min	Max	
Quiescent current	I_{CC}	V_{CC} = 6.0 V; V_{IN} = V_{CC} or GND		1,2,3		160	µA
Input leakage current	I_{IN}	V_{CC} = 6.0 V; V_{IN} = V_{CC} or GND		1,2,3		±1	µA
Functional tests		see 4.3.1d		7			
Propagation delay time A, B, or C to output Y 3/	t_{PHL}	T_C = +25°C C_L = 50 pF ±10%	V_{CC} = 2.0 V	9		115	ns
			V_{CC} = 4.5 V			23	
			V_{CC} = 6.0 V			20	
See figure 3		T_C = -55°C, +125°C C_L = 50 pF ±10%	V_{CC} = 2.0 V	10,11		175	ns
			V_{CC} = 4.5 V			35	
			V_{CC} = 6.0 V			30	
Transition time 4/	t_{THL}, t_{TLH}	T_C = +25°C C_L = 50 pF ±10%	V_{CC} = 2.0 V	9		75	ns
			V_{CC} = 4.5 V			15	
			V_{CC} = 6.0 V			13	
See figure 3		T_C = -55°C, +125°C C_L = 50 pF ±10%	V_{CC} = 2.0 V	10,11		110	ns
			V_{CC} = 4.5 V			22	
			V_{CC} = 6.0 V			19	

See footnotes on next page.

1/ For a power supply of 5 V ±10 percent the worst case output voltage (V_{OH} and V_{OL}) occur for HC at 4.5 V. Thus the 4.5 V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5 V and 4.5 V respectively. (The V_{IH} value at 5.5 V is 3.85 V). The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0 V values should be used. Power dissipation capacitance (C_{PD}), typically 100 pF, determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

2/ Test not required if applied as a forcing function for V_{OH} or V_{OL}.

3/ AC testing at V_{CC} = 2.0 V and V_{CC} = 6.0 V shall be guaranteed, if not tested, to the specified parameters.

4/ Transition time (t_{TLH}, t_{THL}), if not tested, shall be guaranteed to the specified parameters.

3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).

3.8 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).

4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

a. Burn-in test (method 1015 of MIL-STD-883).

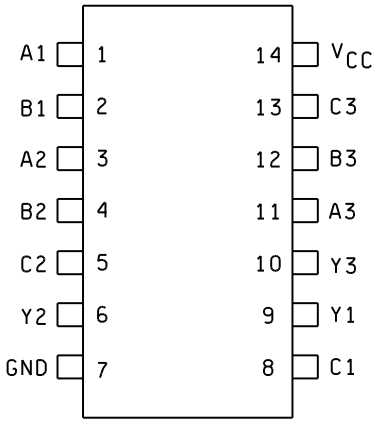
(1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).

(2) T_A = +125°C, minimum.

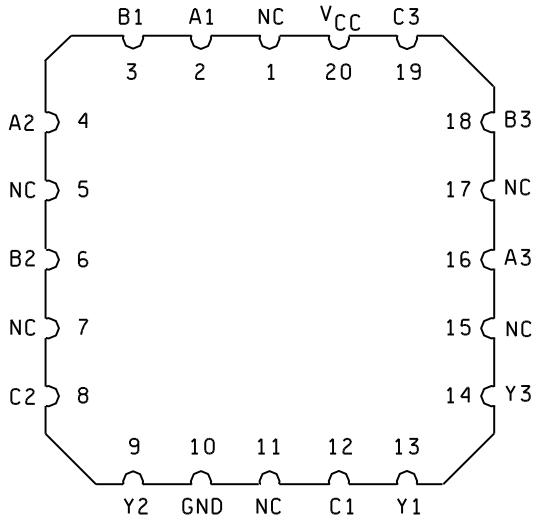
b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

DEVICE TYPE 01

CASES C AND D



CASE 2



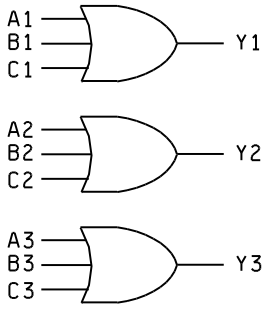


FIGURE 1. **Terminal connections and logic diagram**.

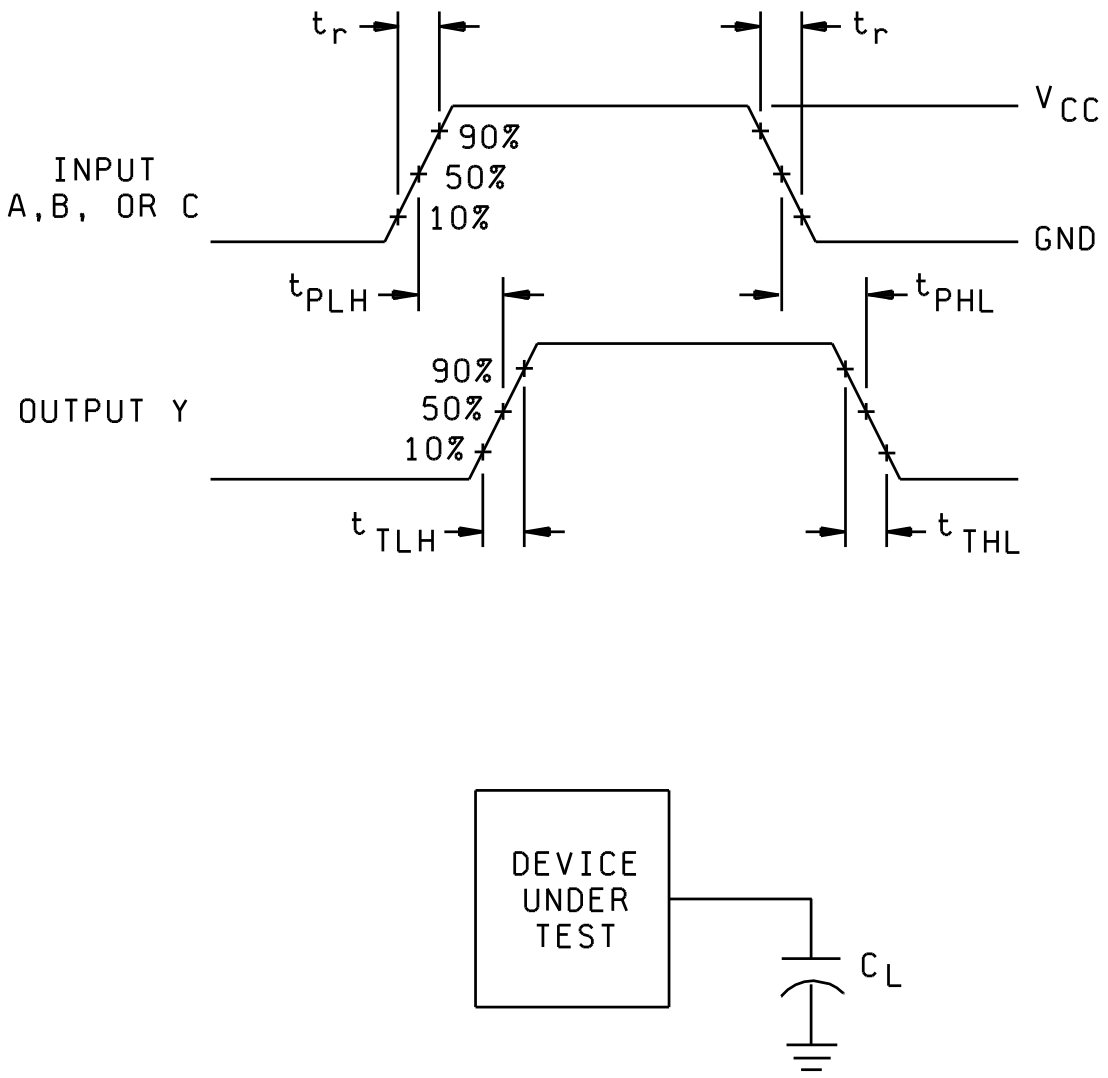


FIGURE 2. Switching time waveforms.

Inputs			Outputs
A	B	C	Y
L	L	L	L
H	X	X	H
X	H	X	H
X	X	H	H

FIGURE 3. Truth table.

4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

a. Tests shall be as specified in table II herein.

b. Subgroups 5, 6, and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.

c. Subgroup 4 (C_{IN} measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance.

d. Subgroup 7 tests sufficiently to verify truth table.

4.3.2 Groups C and D inspections.

a. End-point electrical parameters shall be as specified in table II herein.

b. Steady-state life test (method 1005 of MIL-STD-883) conditions:

(1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).

(2) T_A = +125°C, minimum.

(3) Test duration: 1,000 hours, except as permitted by appendix B of MIL-M-38510 and method 1005 of MIL-STD-883.

TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	---
Final electrical test parameters (method 5004)	1*, 2, 3, 9
Group A test requirements (method 5005)	1, 2, 3, 4, 7, 9, 10, 11**
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3
Additional electrical subgroups for group C periodic inspections	---

* PDA applies to subgroup 1.
** Subgroup 10 and 11, if not tested shall be guaranteed to the specified limits in table I.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.

6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

6.4 Approved sources of supply. Approved sources of supply are listed herein. Additional sources will be added as they become available. The vendors listed herein have agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor 1/ similar part number	Replacement military specification part number
5962-8772201CX	01295 04713 27014 18714	SNJ54HC4075J 54HC4075/BCAJC MM54HC4075J/883 CD54HC4075F/3A	
5962-8772201DX	27014	MM54HC4075E/883	
5962-87722012X	01295 04713 27014	SNJ54HC4075FK 54HC4075M/B2CJC MM54HC4075W/883	

1/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number	Vendor name and address
01295	Texas Instruments Incorporated P.O. Box 6448 Midland, TX 79711
04713	Motorola, Incorporated 7402 South Price Road Tempe, AZ 85283
27014	National Semiconductor Corporation 2900 Semiconductor Drive Santa Clara, CA 95051
18714	GE/RCA Corporation Route 202 Somerville, NJ 08876